

# MOS FIELD EFFECT TRANSISTOR 2SK2541

## N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR HIGH SPEED SWITCHING

#### **DESCRIPTION**

The 2SK2541 is a switching device which can be driven directly by a 1.5 V power source.

The MOS FET has excellent switching characteristics and is suitable for use as a high-speed switching device in digital circuits.

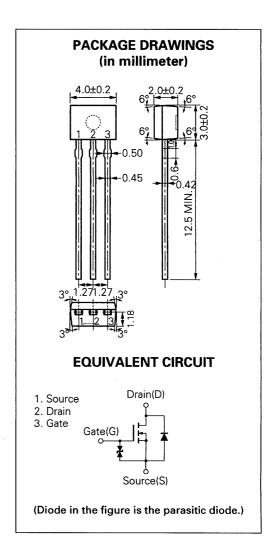
#### **FEATURES**

- Can be driven by a 1.5 V power source.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.

#### **ABSOLUTE MAXIMUM RATINGS (TA = +25 °C)**

Drain to Source Voltage	Voss	50	٧
Gate to Source Voltage	Vgss	±7.0	V
Drain Current (DC)	ID(DC)	±0.1	Α
Drain Current (pulse)	ID(pulse)	±0.2*	Α
<b>Total Power Dissipation</b>	Рт	250	mW
Channel Temperature	Тсн	150	°C
Storage Temperature	Tstg	-55 to +150	°C

<sup>\*</sup>PW ≦10 ms, Duty cycle ≦ 1 %



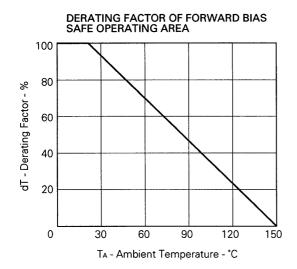
The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

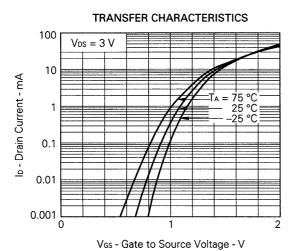


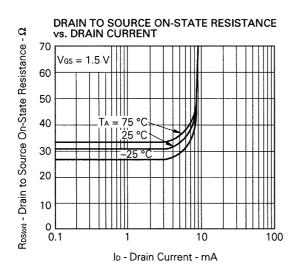
# ELECTRICAL CHARACTERISTICS (TA = +25 °C)

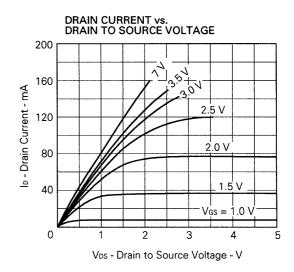
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Cut-off Current	loss			1.0	μΑ	Vps = 50 V, Vgs = 0	
Gate Leakage Current	Igss			±3.0	μΑ	Vgs = ±7.0 V, Vps = 0	
Gate Cut-off Voltage	VGS(off)	0.5	0.7	1.1	٧	$V_{DS} = 3.0 \text{ V, ID} = 1.0 \mu\text{A}$	
Forward Transfer Admittance	yfs	20			mS	Vps = 3.0 V, lp = 10 mA	
Drain to Source On-State Resistance	RDS(on)1		32	50	Ω	Vgs = 1.5 V, lp = 1 mA	
Drain to Source On-State Resistance	RDS(on)2		16	20	Ω	Vgs = 2.5 V, ID = 10 mA	
Drain to Source On-State Resistance	RDS(on)3		12	15	Ω	Vgs = 4.0 V, lp = 10 mA	
Input Capacitance	Ciss		6		pF	Vps = 3.0 V, Vgs = 0 f = 1.0 MHz	
Output Capacitance	Coss		8		pF		
Reverse Transfer Capacitance	Crss		1		pF		
Turn-On Delay Time	td(on)		9		ns	VDD = 3.0 V, ID = 20 mA VGS(on) = 3.0 V, RG = 10 Ω	
Rise Time	tr		48		ns		
Turn-Off Delay Time	td(off)		21		ns		
Fall Time	tf		31		ns	RL = 150 Ω	

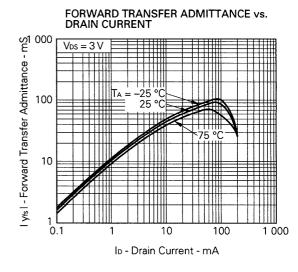
## TYPICAL CHARACTERISTICS (TA = 25 °C)

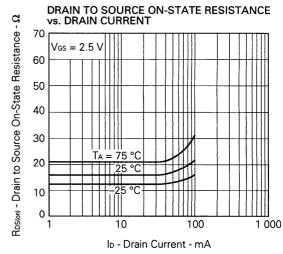


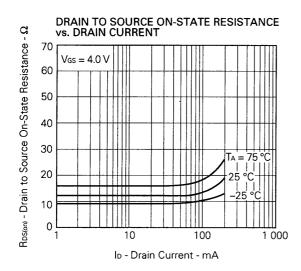


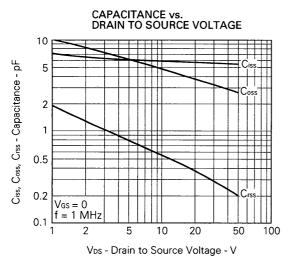


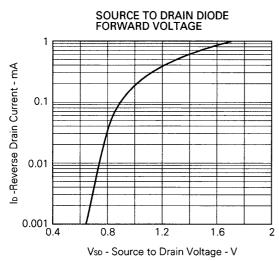


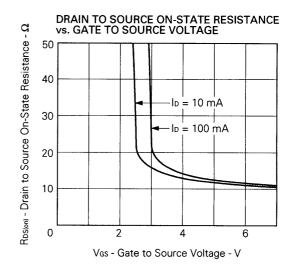


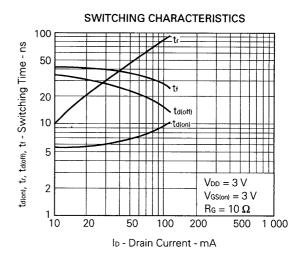














# REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	IEI-1207
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	MF-1134

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Anti-radioactive design is not implemented in this product.

M4 94.11